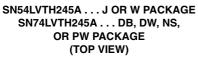
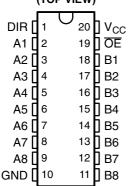
# SN54LVTH245A, SN74LVTH245A 3.3-V ABT OCTAL BUS TRANSCEIVERS WITH 3-STATE OUTPUTS

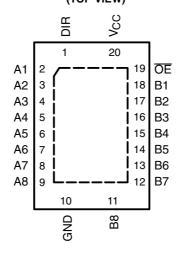
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- Support Mixed-Mode Signal Operation (5-V Input and Output Voltages With 3.3-V V<sub>CC</sub>)
- Typical V<sub>OLP</sub> (Output Ground Bounce)
   <0.8 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C
- Support Unregulated Battery Operation Down to 2.7 V
- I<sub>off</sub> and Power-Up 3-State Support Hot Insertion
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Latch-Up Performance Exceeds 500 mA Per JESD 17
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)

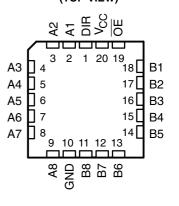




# SN74LVTH245A . . . RGY PACKAGE (TOP VIEW)



# SN54LVTH245A . . . FK PACKAGE (TOP VIEW)



## description/ordering information

These octal bus transceivers are designed specifically for low-voltage (3.3-V) V<sub>CC</sub> operation, but with the capability to provide a TTL interface to a 5-V system environment.

### **ORDERING INFORMATION**

T <sub>A</sub>	PACKAGE	t	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	QFN – RGY	Tape and reel	SN74LVTH245ARGYR	LXH245A
	COIC DW	Tube	SN74LVTH245ADW	LVTHOAFA
	SOIC - DW	Tape and reel	SN74LVTH245ADWR	LVTH245A
	SOP - NS	Tape and reel	SN74LVTH245ANSR	LVTH245A
-40°C to 85°C	SSOP – DB	Tape and reel	SN74LVTH245ADBR	LXH245A
	TOOOD DW	Tube	SN74LVTH245APW	L VI I 0 45 A
	TSSOP – PW	Tape and reel	SN74LVTH245APWR	LXH245A
	VFBGA – GQN	Towns and made	SN74LVTH245AGQNR	L VI I 0 45 A
	VFBGA – ZQN (Pb-free)	Tape and reel	SN74LVTH245AZQNR	LXH245A
	CDIP – J	Tube	SNJ54LVTH245AJ	SNJ54LVTH245AJ
–55°C to 125°C	CFP – W	Tube	SNJ54LVTH245AW	SNJ54LVTH245AW
	LCCC – FK	Tube	SNJ54LVTH245AFK	SNJ54LVTH245AFK

<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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## description/ordering information (continued)

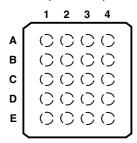
These devices are designed for asynchronous communication between data buses. They transmit data from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable (OE) input can be used to disable the devices so the buses are effectively isolated.

To ensure the high-impedance state during power up or power down,  $\overline{\text{OE}}$  should be tied to  $V_{\text{CC}}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

These devices are fully specified for hot-insertion applications using Ioff and power-up 3-state. The Ioff circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.

#### SN74LVTH245A . . . GQN OR ZQN PACKAGE (TOP VIEW)



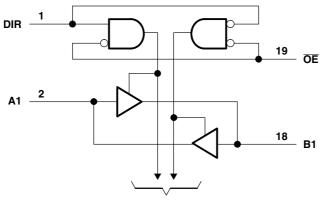
## terminal assignments

	1	2	3	4
Α	A1	DIR	$V_{CC}$	ŌĒ
В	А3	B2	A2	B1
С	<b>A</b> 5	A4	B4	B3
D	A7	B6	A6	B5
Е	GND	A8	B8	B7

#### **FUNCTION TABLE**

INP	UTS	ODEDATION
ŌĒ	DIR	OPERATION
L	L	B data to A bus
L	Н	A data to B bus
Н	Χ	Isolation

## logic diagram (positive logic)



To Seven Other Channels

Pin numbers shown are for the DB, DW, FK, J, NS, PW, RGY, and W packages.



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## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V <sub>CC</sub>	–0.5 V to 4.6 V
Input voltage range, V <sub>I</sub> (see Note 1)	
Voltage range applied to any output in the high-impedance	
or power-off state, V <sub>O</sub> (see Note 1)	–0.5 V to 7 V
Voltage range applied to any output in the high state, V <sub>O</sub> (see Note 1)	0.5 V to V <sub>CC</sub> + 0.5 V
Current into any output in the low state, I <sub>O</sub> : SN54LVTH245A	96 mA
SN74LVTH245A	128 mA
Current into any output in the high state, I <sub>O</sub> (see Note 2): SN54LVTH245A	48 mA
SN74LVTH245A	64 mA
Input clamp current, I <sub>IK</sub> (V <sub>I</sub> < 0)	–50 mA
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0)	–50 mA
Package thermal impedance, $\theta_{JA}$ (see Note 3): DB package	70°C/W
(see Note 3): DW package	58°C/W
(see Note 3): GQN/ZQN package	78°C/W
(see Note 3): NS package	60°C/W
(see Note 3): PW package	83°C/W
(see Note 4): RGY package	37°C/W
Storage temperature range, T <sub>stg</sub>	–65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

- 2. This current flows only when the output is in the high state and  $V_O > V_{CC}$ .
- 3. The package thermal impedance is calculated in accordance with JESD 51-7.
- 4. The package thermal impedance is calculated in accordance with JESD 51-5.

## recommended operating conditions (see Note 5)

			SN54LVT	H245A	SN74LVT	H245A	
			MIN	MAX	MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		2.7	3.6	2.7	3.6	V
V <sub>IH</sub>	High-level input voltage		2		2		V
V <sub>IL</sub>	Low-level input voltage			0.8		0.8	V
VI	Input voltage			5.5		5.5	V
I <sub>OH</sub>	High-level output current			-24		-32	mA
I <sub>OL</sub>	Low-level output current			48		64	mA
Δt/Δν	Input transition rise or fall rate	Outputs enabled		10		10	ns/V
$\Delta t/\Delta V_{CC}$	Power-up ramp rate		200		200		μs/V
T <sub>A</sub>	Operating free-air temperature		-55	125	-40	85	°C

NOTE 5: All unused control inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



# SN54LVTH245A, SN74LVTH245A 3.3-V ABT OCTÁL BUS TRANSCEIVERS WITH 3-STATE OUTPUTS

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## electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DAI	DAMETER	TECT O	ONDITIONS	SN5	4LVTH2	45A	SN7	4LVTH2	45A	UNIT
PAI	RAMETER	TEST C	ONDITIONS	MIN	TYP†	MAX	MIN	TYP†	MAX	UNII
V <sub>IK</sub>		$V_{CC} = 2.7 \text{ V},$	$I_I = -18 \text{ mA}$			-1.2			-1.2	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V},$	$I_{OH} = -100  \mu A$	V <sub>CC</sub> -0.	2		V <sub>CC</sub> -0.	2		
, ,		$V_{CC} = 2.7 \text{ V},$	$I_{OH} = -8 \text{ mA}$	2.4			2.4			V
V <sub>OH</sub>		V 0.V	$I_{OH} = -24 \text{ mA}$	2						V
		V <sub>CC</sub> = 3 V	$I_{OH} = -32 \text{ mA}$				2			
		V <sub>CC</sub> = 2.7 V	$I_{OL} = 100 \mu\text{A}$			0.2			0.2	
		V <sub>CC</sub> = 2.7 V	$I_{OL} = 24 \text{ mA}$			0.5			0.5	
l ,,			I <sub>OL</sub> = 16 mA			0.4			0.4	٧
V <sub>OL</sub>		V <sub>CC</sub> = 3 V	$I_{OL} = 32 \text{ mA}$			0.5			0.5	V
		V <sub>CC</sub> = 3 V	$I_{OL} = 48 \text{ mA}$			0.55				
			$I_{OL} = 64 \text{ mA}$						0.55	
	Control inputs	$V_{CC} = 3.6 \text{ V},$	$V_I = V_{CC}$ or GND			±1			±1	
	Control inputs	$V_{CC} = 0 \text{ or } 3.6 \text{ V},$	$V_{I} = 5.5 \text{ V}$			10			10	
l <sub>i</sub>			$V_{I} = 5.5 \text{ V}$			20			20	μΑ
	A or B ports‡	V <sub>CC</sub> = 3.6 V	$V_I = V_{CC}$			1			1	
			$V_I = 0$			-5			-5	
I <sub>off</sub>		$V_{CC} = 0$ ,	$V_I$ or $V_O = 0$ to 4.5 V						±100	μΑ
		V <sub>CC</sub> = 3 V	$V_{I} = 0.8 V$	75			75			
I <sub>I(hold)</sub>	A or B ports	vCC = 3 v	V <sub>I</sub> = 2 V	-75			-75			μA
-i(noid)	Troi 2 ponto	V <sub>CC</sub> = 3.6 V <sup>§</sup> ,	$V_{I} = 0 \text{ to } 3.6 \text{ V}$						500 -750	į.
I <sub>OZPU</sub>		$V_{CC} = 0$ to 1.5 V, $V_{O} = 0$ $\overline{OE} = \text{don't care}$	0.5 V to 3 V,			±100*			±100	μА
I <sub>OZPD</sub>		$V_{CC}$ = 1.5 V to 0, $V_{O}$ = $\overline{OE}$ = don't care	0.5 V to 3 V,			±100*			±100	μΑ
		V <sub>CC</sub> = 3.6 V,	Outputs high			0.19			0.19	
I <sub>CC</sub>		$I_{O} = 0$ ,	Outputs low			5			5	mA
		$V_I = V_{CC}$ or GND	Outputs disabled			0.19			0.19	
Δl <sub>CC</sub> ¶		$V_{CC} = 3 \text{ V to } 3.6 \text{ V, One}$ Other inputs at $V_{CC}$ or $0$				0.2			mA	
C <sub>i</sub>		V <sub>I</sub> = 3 V or 0			4			4		pF
C <sub>io</sub>		V <sub>O</sub> = 3 V or 0			9			9		pF

<sup>\*</sup> On products compliant to MIL-PRF-38535, this parameter is not production tested.



 $<sup>^{\</sup>dagger}$  All typical values are at  $V_{CC}$  = 3.3 V,  $T_{A}$  = 25°C.

<sup>&</sup>lt;sup>‡</sup> Unused terminals are at V<sub>CC</sub> or GND.

<sup>§</sup> This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

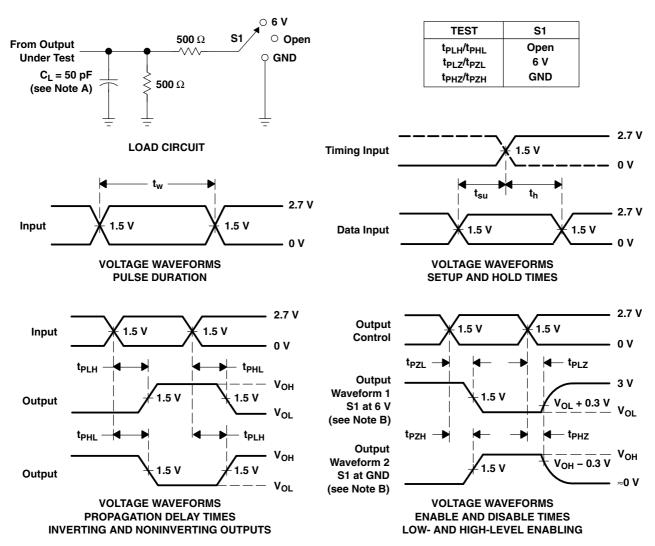
 $<sup>\</sup>P$  This is the increase in supply current for each input that is at the specified TTL voltage level, rather than  $V_{CC}$  or GND.

# switching characteristics over recommended operating free-air temperature range, $C_L$ = 50 pF (unless otherwise noted) (see Figure 1)

			;	SN54LVTH245A				SN7	4LVTH2	45A		
PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC}$ = 3.3 V $\pm$ 0.3 V		V <sub>CC</sub> = 2.7 V		$V_{CC}$ = 3.3 V $\pm$ 0.3 V			V <sub>CC</sub> =	UNIT	
			MIN	MAX	MIN	MAX	MIN	TYP†	MAX	MIN	MAX	
t <sub>PLH</sub>	A or B	D or A	0.7	3.7		4.2	1.2	2.3	3.5		4	
t <sub>PHL</sub>	A or B	B or A	0.7	3.7		4.2	1.2	2.1	3.5		4	ns
t <sub>PZH</sub>	ŌĒ	A or D	1.2	5.7		7.4	1.3	3.2	5.5		7.1	20
t <sub>PZL</sub>	OE	A or B	1.6	5.7		6.8	1.7	3.4	5.5		6.5	ns
t <sub>PHZ</sub>	ŌĒ	A or B	1.8	6.2	·	6.8	2.2	3.5	5.9		6.5	
t <sub>PLZ</sub>	SE	AOLR	1.8	5.3		5.5	2.2	3.4	5		5.1	ns

 $<sup>^{\</sup>dagger}$  All typical values are at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C.

#### PARAMETER MEASUREMENT INFORMATION



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_{Q}$  = 50  $\Omega$ ,  $t_{r} \leq$  2.5 ns,  $t_{f} \leq$  2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms





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## **PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9564201Q2A	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9564201Q2A SNJ54LVTH 245AFK	Samples
5962-9564201QRA	ACTIVE	CDIP	J	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9564201QR A SNJ54LVTH245AJ	Samples
5962-9564201QSA	ACTIVE	CFP	W	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9564201QS A SNJ54LVTH245AW	Samples
5962-9564201V2A	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9564201V2A SNV54LVTH 245AFK	Samples
5962-9564201VRA	ACTIVE	CDIP	J	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9564201VR A SNV54LVTH245AJ	Samples
5962-9564201VSA	ACTIVE	CFP	W	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9564201VS A SNV54LVTH245AW	Samples
SN74LVTH245ADBR	ACTIVE	SSOP	DB	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LXH245A	Samples
SN74LVTH245ADW	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH245A	Samples
SN74LVTH245ADWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH245A	Samples
SN74LVTH245ADWRG4	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH245A	Samples
SN74LVTH245ANSR	ACTIVE	SO	NS	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVTH245A	Samples
SN74LVTH245ANSRG4	ACTIVE	SO	NS	20	2000	TBD	Call TI	Call TI	-40 to 85		Samples
SN74LVTH245APW	ACTIVE	TSSOP	PW	20	70	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LXH245A	Samples
SN74LVTH245APWE4	ACTIVE	TSSOP	PW	20	70	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LXH245A	Samples
SN74LVTH245APWG4	ACTIVE	TSSOP	PW	20	70	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LXH245A	Samples



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Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LVTH245APWR	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 85	LXH245A	Samples
SN74LVTH245APWRE4	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LXH245A	Samples
SN74LVTH245APWRG4	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LXH245A	Samples
SN74LVTH245ARGYR	ACTIVE	VQFN	RGY	20	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	LXH245A	Samples
SNJ54LVTH245AFK	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9564201Q2A SNJ54LVTH 245AFK	Samples
SNJ54LVTH245AJ	ACTIVE	CDIP	J	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9564201QR A SNJ54LVTH245AJ	Samples
SNJ54LVTH245AW	ACTIVE	CFP	W	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9564201QS A SNJ54LVTH245AW	Samples

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

## PACKAGE OPTION ADDENDUM

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(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

#### OTHER QUALIFIED VERSIONS OF SN54LVTH245A, SN54LVTH245A-SP, SN74LVTH245A:

Catalog: SN74LVTH245A, SN54LVTH245A

Enhanced Product: SN74LVTH245A-EP, SN74LVTH245A-EP

Military: SN54LVTH245A

Space : SN54LVTH245A-SP

#### NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Enhanced Product Supports Defense, Aerospace and Medical Applications
- Military QML certified for Military and Defense Applications
- Space Radiation tolerant, ceramic packaging and qualified for use in Space-based application

# **PACKAGE MATERIALS INFORMATION**

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## TAPE AND REEL INFORMATION





	-
A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVTH245ADBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74LVTH245ADWR	SOIC	DW	20	2000	330.0	24.4	10.9	13.3	2.7	12.0	24.0	Q1
SN74LVTH245ANSR	SO	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74LVTH245APWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
SN74LVTH245APWRG4	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
SN74LVTH245ARGYR	VQFN	RGY	20	3000	330.0	12.4	3.8	4.8	1.6	8.0	12.0	Q1



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## \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVTH245ADBR	SSOP	DB	20	2000	356.0	356.0	35.0
SN74LVTH245ADWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74LVTH245ANSR	SO	NS	20	2000	367.0	367.0	45.0
SN74LVTH245APWR	TSSOP	PW	20	2000	356.0	356.0	35.0
SN74LVTH245APWRG4	TSSOP	PW	20	2000	367.0	367.0	38.0
SN74LVTH245ARGYR	VQFN	RGY	20	3000	356.0	356.0	35.0

# **PACKAGE MATERIALS INFORMATION**

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## **TUBE**



\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
5962-9564201Q2A	FK	LCCC	20	1	506.98	12.06	2030	NA
5962-9564201V2A	FK	LCCC	20	1	506.98	12.06	2030	NA
5962-9564201VSA	W	CFP	20	1	506.98	26.16	6220	NA
SN74LVTH245ADW	DW	SOIC	20	25	507	12.83	5080	6.6
SN74LVTH245APW	PW	TSSOP	20	70	530	10.2	3600	3.5
SN74LVTH245APWE4	PW	TSSOP	20	70	530	10.2	3600	3.5
SN74LVTH245APWG4	PW	TSSOP	20	70	530	10.2	3600	3.5
SNJ54LVTH245AFK	FK	LCCC	20	1	506.98	12.06	2030	NA

# W (R-GDFP-F20)

# CERAMIC DUAL FLATPACK



- A. All linear dimensions are in inches (millimeters).
- This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.

  D. Index point is provided on cap for terminal identification only.

  E. Falls within Mil—Std 1835 GDFP2—F20







- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



# PW (R-PDSO-G20)

# PLASTIC SMALL OUTLINE



- All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
  C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



# FK (S-CQCC-N\*\*)

# LEADLESS CERAMIC CHIP CARRIER

28 TERMINAL SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a metal lid.
- D. Falls within JEDEC MS-004







- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



## **MECHANICAL DATA**

# NS (R-PDSO-G\*\*)

# 14-PINS SHOWN

## PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



# 14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

3.5 x 4.5, 0.5 mm pitch

PLASTIC QUAD FGLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





PLASTIC QUAD FLATPACK - NO LEAD



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
  2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.





SOIC



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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